BSS123LT1G, BVSS123LT1G

Power MOSFET 170 mAmps, 100 Volts

N-Channel SOT-23

Features

- BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	±20 ±40	Vdc Vpk
Drain Current – Continuous (Note 1) – Pulsed (Note 2)	I _D I _{DM}	0.17 0.68	Adc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 3) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{ hetaJA}$	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

1. The Power Dissipation of the package may result in a lower continuous drain current.

2. Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

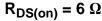
3. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

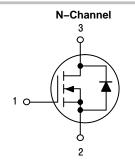


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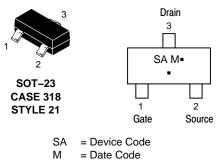
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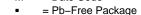
170 mAMPS 100 VOLTS





MARKING DIAGRAM & PIN ASSIGNMENT





(*Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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BSS123LT1G, BVSS123LT1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

teristic	Symbol	Min	Тур	Max	Unit
	·	•	•		
	V _{(BR)DSS}	100	-	-	Vdc
	IDSS		_	15 60	μAdc
	I _{GSS}	-	-	50	nAdc
	V _{GS(th)}	1.6	-	2.6	Vdc
Static Drain–Source On–Resistance (V _{GS} = 10 Vdc, I _D = 100 mAdc)		-	-	6.0	Ω
Forward Transconductance $(V_{DS} = 25 \text{ Vdc}, I_D = 100 \text{ mAdc})$		80	-	-	mmhos
	C _{iss}	-	20	-	pF
	C _{oss}	-	9.0	-	pF
Reverse Transfer Capacitance ($V_{DS} = 25$ Vdc, $V_{GS} = 0$, f = 1.0 MHz)		-	4.0	-	pF
$(V_{CC} = 30 \text{ Vdc}, I_C = 0.28 \text{ Adc}, \\ V_{GS} = 10 \text{ Vdc}, R_{GS} = 50 \Omega)$	t _{d(on)}	_	20	-	ns
	t _{d(off)}	-	40	-	ns
Diode Forward On–Voltage $(I_D = 0.34 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$		-	-	1.3	V
		$V_{(BR)DSS}$ I_{DSS} I_{GSS} $V_{GS(th)}$ $r_{DS(on)}$ g_{fs} C_{iss} C_{iss} C_{rss} C_{rss} $V_{Cc} = 30 Vdc, I_{C} = 0.28 \text{ Adc}, \qquad t_{d(on)}$	$\begin{array}{c c c c c c c c } V_{(BR)DSS} & 100 \\ & & & & \\ & $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c cccc} V_{(BR)DSS} & 100 & - & - \\ & & & & \\ & & $

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

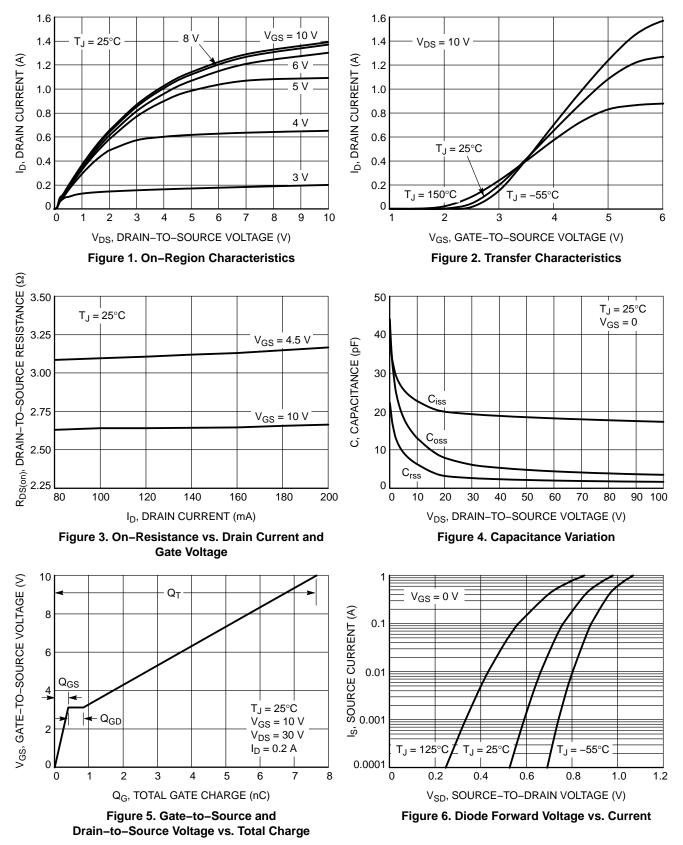
Device	Package	Shipping [†]
BSS123LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
BSS123LT3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
BVSS123LT1G*	SOT-23 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*BVSS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable.

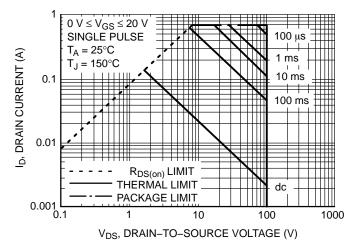
BSS123LT1G, BVSS123LT1G

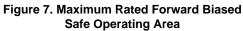
TYPICAL ELECTRICAL CHARACTERISTICS

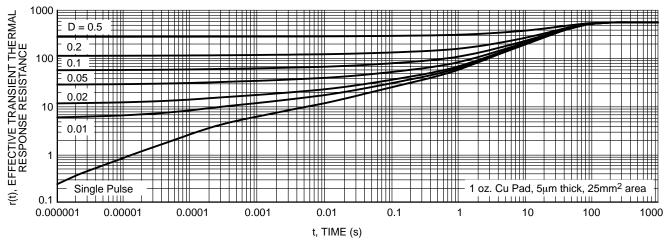


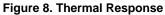
BSS123LT1G, BVSS123LT1G

TYPICAL ELECTRICAL CHARACTERISTICS



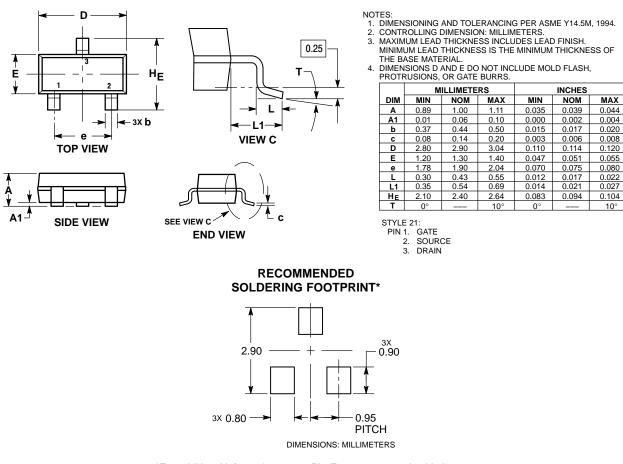






PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AR



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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